EClamp2376P ESD/EMI Protection for Color LCD Interfaces

PROTECTION PRODUCTS - EMIClamp™

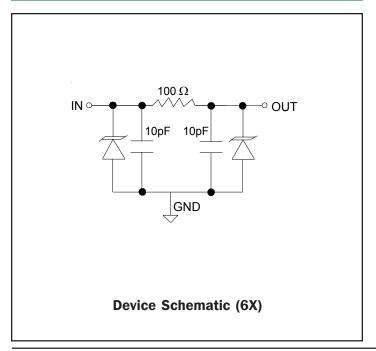
Description

The EClamp™2376P is a low pass filter array with integrated TVS diodes. It is designed to suppress unwanted EMI/RFI signals and provide electrostatic discharge (ESD) protection in portable electronic equipment. This state-of-the-art device utilizes solid-state silicon-avalanche technology for superior clamping performance and DC electrical characteristics. They have been optimized for **protection of color LCD panels** in cellular phones and other portable electronics.

The device consists of six identical circuits comprised of TVS diodes for ESD protection, and a resistor - capacitor network for EMI/RFI filtering. A series resistor value of 100Ω and a capacitance value of 10pF are used to achieve 30dB minimum attenuation from 1.8GHz to 2.5GHz. The TVS diodes provide effective suppression of ESD voltages in excess of $\pm 15kV$ (air discharge) and $\pm 8kV$ (contact discharge) per IEC 61000-4-2, level 4.

The EClamp2376P is in a 12-pin, RoHS compliant, SLP3016P12 package. It measures $3.0 \times 1.6 \times 0.58$ mm. The leads are spaced at a pitch of 0.5mm and are finished with lead-free NiPd. The small package makes it ideal for use in portable electronics such as cell phones, digital still cameras, and PDAs.

Circuit Diagram (Each Line)



Features

- Bidirectional EMI/RFI filter with integrated TVS for ESD protection
- ◆ ESD protection to IEC 61000-4-2 (ESD) Level 4, ±15kV (air), ±8kV (contact)
- Filter performance: 30dB minimum attenuation
 1.8GHz to 2.5GHz
- TVS working voltage: 5V
 Resistor: 100Ω +/- 15%
- ◆ Typical Capacitance: 20pF (VR = 0V)
- Protection and filtering for six lines
- Solid-state technology

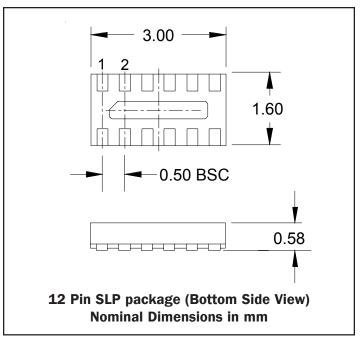
Mechanical Characteristics

- ◆ SLP3016P12 12-pin package
- RoHS/WEEE Compliant
- Nominal Dimensions: 3.0 x 1.6 x 0.58 mm
- ◆ Lead Pitch: 0.5mm
- Lead finish: NiPd
- Marking : Marking Code
- Packaging: Tape and Reel per EIA 481.

Applications

- Color LCD Protection
- ◆ Cell Phone CCD Camera Lines
- Clamshell Cell Phones

Package Configuration





Maximum Ratings

Rating	Symbol	Value	Units
ESD per IEC 61000-4-2 (Air) ESD per IEC 61000-4-2 (Contact)	V _{ESD}	+/- 17 +/- 12	kV
Junction Temperature	T,	125	°C
Operating Temperature	T _{op}	-40 to +85	°C
Storage Temperature	T _{STG}	-55 to +150	°C

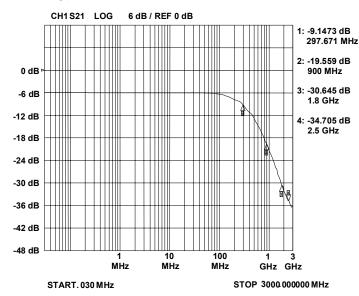
Electrical Characteristics (T = 25°C)

Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
TVS Reverse Stand-Off Voltage	$V_{_{\mathrm{RWM}}}$				5	V
TVS Reverse Breakdown Voltage	V_{BR}	I _t = 1mA	6	8	10	V
TVS Reverse Leakage Current	I _R	V _{RWM} = 3.0V			0.5	μΑ
Total Series Resistance	R	Each Line	85	100	115	Ohms
Total Capacitance	C _{in}	Input to Gnd, Each Line V _R = OV, f = 1MHz	16	20	24	pF
Total Capacitance	C _{in}	Input to Gnd, Each Line V _R = 2.5V, f = 1MHz	9	11	13	pF

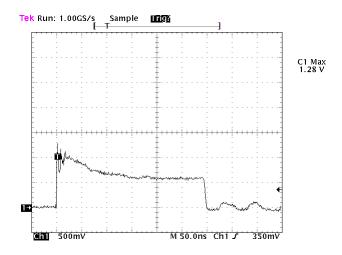


Typical Characteristics

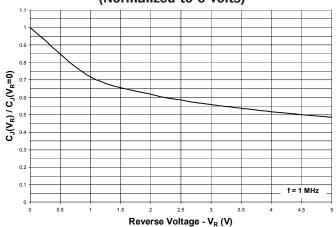
Typical Insertion Loss S21 (Each Line)



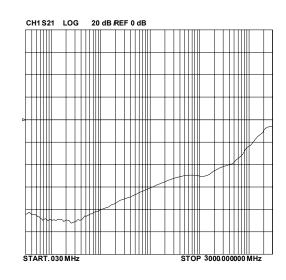
ESD Clamping (+8kV Contact)



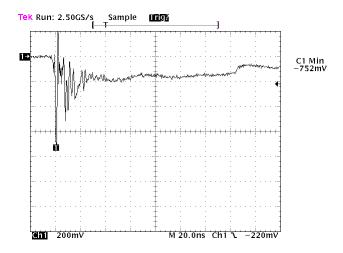
Capacitance vs. Reverse Voltage (Normalized to 0 volts)



Analog Crosstalk (Each Line)



ESD Clamping (-8kV Contact)





Device Connection

The EClamp2376P is comprised of six identical circuits each consisting of a low pass filter for EMI/RFI suppression and dual TVS diodes for ESD protection. The device is in a 12-pin SLP package. Electrical connection is made to the 12 pins located at the bottom of the device. A center tab serves as the ground connection. The device has a flow through design for easy layout. Pin connections are noted in Figure 1. All path lengths should be kept as short as possible to minimize the effects of parasitic inductance in the board traces. Recommendations for the ground connection are given below.

Ground Connection Recommendation

Parasitic inductance present in the board layout will affect the filtering performance of the device. As frequency increases, the effect of the inductance becomes more dominant. This effect is given by Equation 1.

Equation 1: The Impedance of an Inductor at Frequency XLF

 $XLF(L, f) = 2 * \pi * f * L$

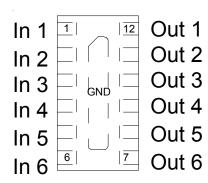
Where:

L= Inductance (H)

f = Frequency (Hz)

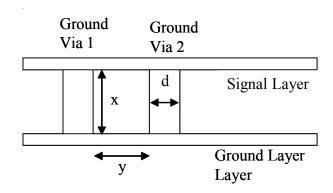
Via connections to the ground plane form rectangular wire loops or ground loop inductance as shown in Figure 2. Ground loop inductance can be reduced by using multiple vias to make the connection to the ground plane. Bringing the ground plane closer to the signal layer (preferably the next layer) also reduces ground loop inductance. Multiple vias in the device ground pad will result in a lower inductive ground loop over two exterior vias. Vias with a diameter d are separated by a distance y run between layers separated by a distance x. The inductance of the loop path is given by Equation 2. Thus, decreasing distance x and y will reduce the loop inductance and result in better high frequency filter characteristics.

Figure 1 - Pin Identification and Configuration (Top Side View)



Pin	Identification
1 - 6	Input Lines
7 - 12	Output Lines
Center Tab	Ground

Figure 2 - Inductance of Rectangular Wire Loops



Equation 2: Inductance of Rectangular Wire Loop

LRECT(d, x, y) =
$$10.16 * 10^{-9} * \left[x * ln \left[\frac{2*y}{d} \right] + y * ln \left[\frac{2*x}{d} \right] \right]$$

Where:

d = Diameter of the wire (in)

x = Length of wire loop (in)

y = Breath of wire loop (in)



Applications Information

Figure 3 shows the recommended device layout. The ground pad vias have a diameter of 0.008 inches (0.20 mm) while the two external vias have a diameter of 0.010 inches (0.250mm). The internal vias are spaced approximately evenly from the center of the pad. The designer may choose to use more vias with a smaller diameter (such as 0.005 inches or 0.125mm) since changing the diameter of the via will result in little change in inductance (i.e. the log function in Equation 2 in highly insensitive to parameter d). Figure 4 shows a typical insertion loss (S21) plot for the device using Semtech's filter evaluation board with 50 Ohm traces and the recommended via configuration. Figure 5 shows a typical insertion loss (S21) plot using a similar board without the internal ground pad vias. The result is a more inductive ground loop. Note the "hump" at a frequency of 2.5GHz. This is the resonant frequency of the higher ground loop inductance.

Figure 3 - Recommended Layout Using Ground Vias

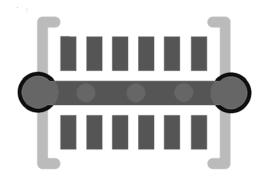


Figure 4 - Filter Characteristics Using Recommended Layout with Internal Vias

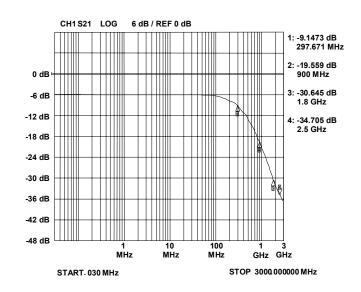
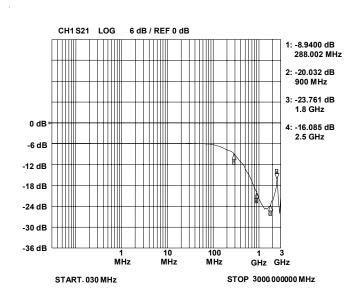


Figure 5 - Filter Characteristics Using Layout without Internal Ground Vias





Applications Information - Spice Model

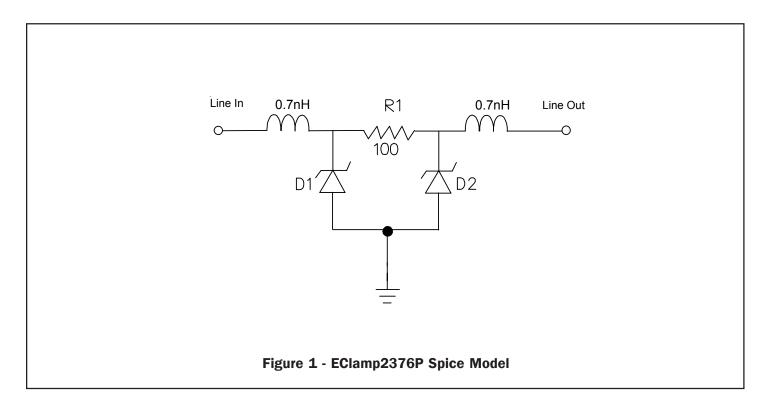
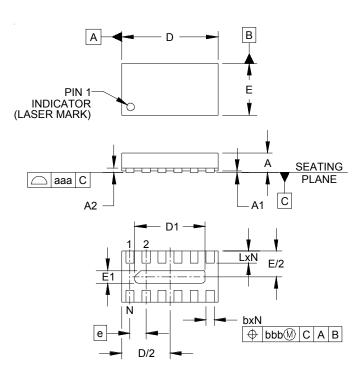


Table 1 - EClamp2376P Spice Parameters						
Parameter	Unit	D1 (TVS)	D2 (TVS)			
IS	Amp	2E-15	2E-15			
BV	Volt	7.42	7.42			
٧J	Volt	0.775	0.775			
RS	Ohm	1.00	1.00			
IBV	Amp	1E-3	1E-3			
C10	Farad	9.8E-12	9.8E-12			
TT	sec	2.541E-9	2.541E-9			
М		0.246	0.246			
N		1.1	1.1			
EG	eV	1.11	1.11			



Outline Drawing - SLP3016P12

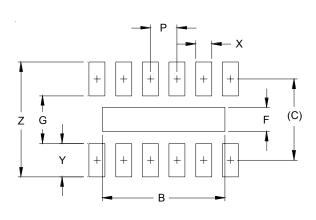


DIMENSIONS						
	11	NCHE	S	MILL	IMET	ERS
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	.020	.023	.026	0.50	0.58	0.65
A1	.000	.001	.002	0.00	.003	0.05
A2		(.006)			(0.15)	
b	.007	.010	.012	0.20	0.25	0.30
D	.114	.118	.122	2.90	3.00	3.10
D1	.083	.087	.091	2.10	2.20	2.30
E	.059	.063	.067	1.50	1.60	1.70
E1	.010	.016	.020	0.25	0.40	0.50
е	.0	20 BS	C	0.	50 BS	C
L	.011	.013	.015	0.28	0.33	0.38
N		12			12	
aaa		.003			0.08	
bbb		.004			0.10	

NOTES:

- 1. CONTROLLING DIMENSIONS ARE IN MILLIMETERS (ANGLES IN DEGREES).
- 2. COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS.

Land Pattern - SLP3016P12



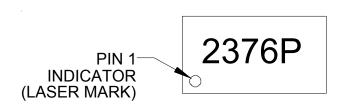
	DIMENSIONS						
DIM	INCHES	MILLIMETERS					
В	.091	2.30					
С	.060	1.52					
F	.018	0.45					
G	.035	0.89					
Р	.020	0.50					
X	.012	0.30					
Υ	.025	0.63					
Z	.085	2.15					

NOTES:

THIS LAND PATTERN IS FOR REFERENCE PURPOSES ONLY.
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Marking

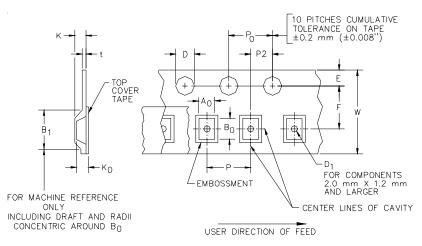


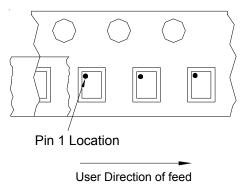
Ordering Information

Part Number	Qty per Reel	Reel Size	
EClamp2376P.TCT	3000	7 Inch	

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Tape and Reel Specification





Device Orientation in Tape

A0	во	ко
1.78 +/-0.05 mm	3.18 +/-0.05 mm	0.76 +/-0.05 mm

Tape Width	B, (Max)	D	D1	E	F	K (MAX)	Р	PO	P2	T(MAX)	W
8 mm	4.2 mm (.165)	1.5 + 0.1 mm - 0.0 mm (0.59 +.005 000)	0.8 mm ±0.05 (.031)	1.750±.10 mm (.069±.004)	3.5±0.05 mm (.138±.002)	2.4 mm (.094)	4.0±0.1 mm (.157±.00- 4)	4.0±0.1 mm (.157±.00- 4)	2.0±0.05m- m (.079±.002)	0.4 mm (.016)	8.0 mm + 0.3 mm - 0.1 mm (.312±.012)

Contact Information for Semtech International AG

Taiwan Branch	Tel: 886-2-2748-3380 Fax: 886-2-2748-3390	Semtech Switzerland GmbH Japan Branch	Tel: 81-3-6408-0950 Fax: 81-3-6408-0951
Korea Branch	Tel: 82-2-527-4377 Fax: 82-2-527-4376	Semtech Limited (U.K.)	Tel: 44-1794-527-600 Fax: 44-1794-527-601
Shanghai Office	Tel: 86-21-6391-0830 Fax: 86-21-6391-0831	Semtech France SARL	Tel: 33-(0)169-28-22-00 Fax: 33-(0)169-28-12-98
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82356240030 VESD12A1A-HD1-GS08 CPDUR5V0R-HF CPDUR24V-HF CPDQC5V0U-HF CPDQC5V0USP-HF CPDQC5V0-HF
D1213A-01LP4-7B D1213A-02WL-7 ESDLIN1524BJ-HQ 5KP100A 5KP15A